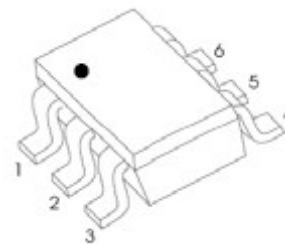
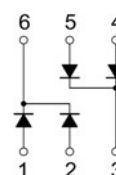


SCHOTTKY BARRIER DIODE ARRAYS FEATURES

- Low Forward Voltage Drop
- Fast Switching
- Small Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection
- Available in Lead Free Version



SOT-363



Marking: KL7

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

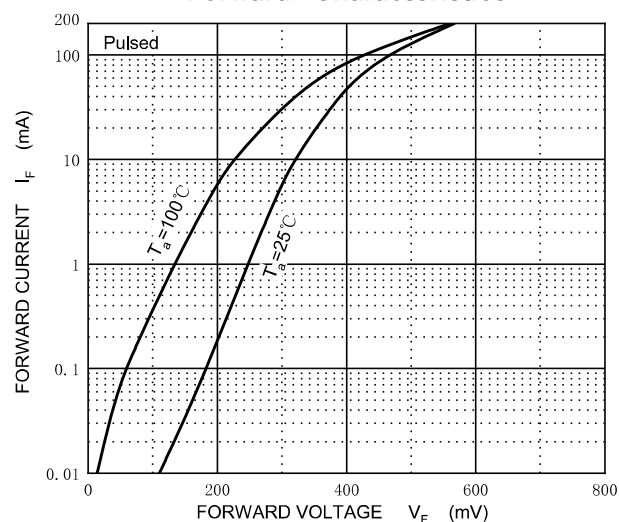
Symbol	Parameter	Value	Unit
V_{RRM}	Repetitive Peak Reverse Voltage	30	V
V_{RWM}	Peak Working Reverse Voltage		
V_R	DC Blocking Voltage		
I_o	Forward Continuous Current	200	mA
I_{FRM}	Repetitive Peak Forward Current	300	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$	600	
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	500	$^{\circ}\text{C/W}$
T_j	Operating Junction Temperature Range	$-40 \sim +125$	$^{\circ}\text{C}$
T_{stg}	Storage Temperature Range	$-55 \sim +150$	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

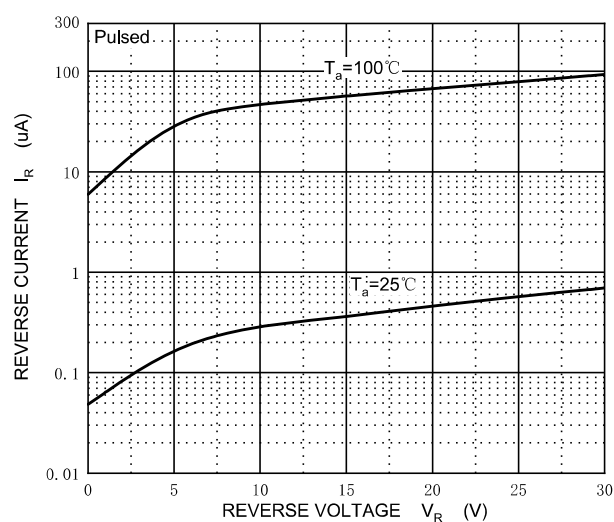
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=100\mu\text{A}$	30			V
Reverse current	I_R	$V_R=25\text{V}$			2	μA
Forward voltage	V_F	$I_F=1\text{mA}$			320	mV
		$I_F=10\text{mA}$			400	
		$I_F=30\text{mA}$			500	
		$I_F=100\text{mA}$			1000	
Total capacitance	C_{tot}	$V_R=1\text{V}, f=1\text{MHz}$			10	pF
Reverse recovery time	t_{rr}	$I_F=I_R=10\text{mA}, I_{rr}=0.1 \times I_R, R_L=100\Omega$			5	ns

Typical Characteristics

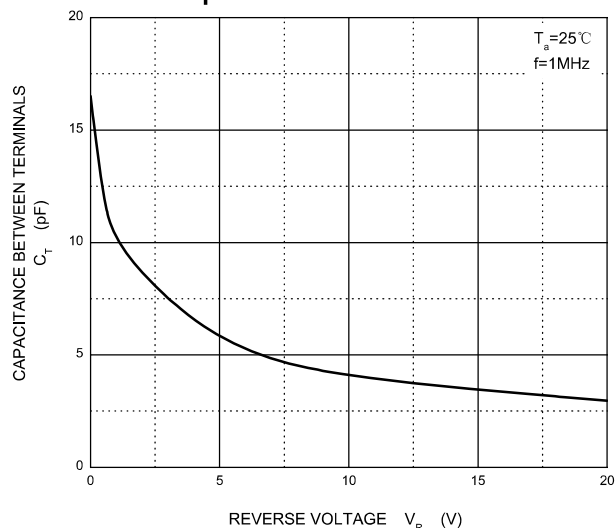
Forward Characteristics



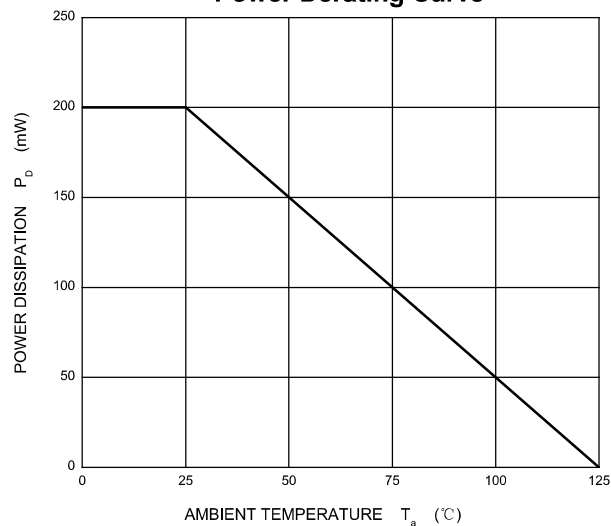
Reverse Characteristics



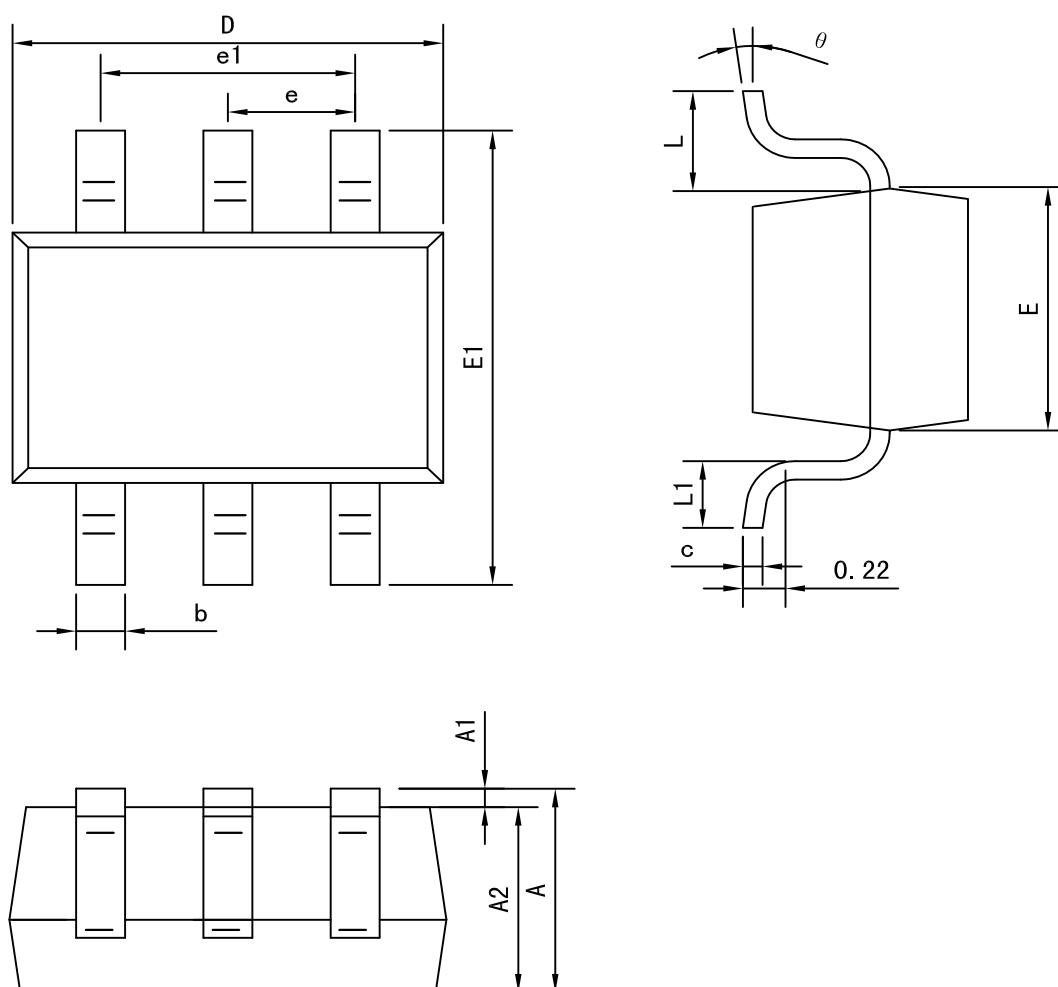
Capacitance Characteristics



Power Derating Curve



SOT-363 Package outline dimensions



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
θ	0°	8°